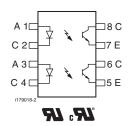
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# Optocoupler, Phototransistor Output, Dual Channel, **SOIC-8 Package**





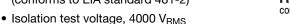
#### **DESCRIPTION**

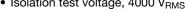
The ILD205T, ILD206T, ILD207T, ILD211T, ILD213T, ILD217T are optically coupled pairs with a gallium arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD205T, ILD206T, ILD207T, ILD211T, ILD213T, ILD217T come in a standard SOIC-8 small outline package for surface mounting which makes it ideally suited for high density applications with limited through-holes space. addition to eliminating requirements, this package conforms to standards for surface mounted devices.

A specified minimum and maximum CTR allows a narrow tolerance in the electrical design of the adjacent circuits. The high BV<sub>CEO</sub> of 70 V gives a higher safety margin compared to the industry standard of 30 V.

#### **FEATURES**

- Two channel coupler
- SOIC-8 surface mountable package
- Standard lead spacing of 0.05"
- · Available only on tape and reel option (conforms to EIA standard 481-2)





- · Compatible with dual wave, vapor phase and IR reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- cUL file no. E52744, equivalent to CSA bulletin 5A

ORDERING INFORMATIO	N					
	D 2	#	#	Т	SIG	DC-8
	PART NUMBER  6.1 mm					
AGENCY CERTIFIED/PACKAGE			CTR	ł (%)		
AGENCY CERTIFIED/PACKAGE		10 mA 1				
UL, cUL	40 to 80	63 to 125	100 to 200	≥ 20	≥ 100	≥ 100
SOIC-8	ILD205T	ILD206T	ILD207T	ILD211T	ILD213T	ILD217T

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER TEST CONDITION SYMBOL VALUE UNIT								
INPUT								
Peak reverse voltage		$V_R$	6	V				
Peak pulsed current	1 µs, 300 pps		1	Α				
Continuous forward current per channel		l <sub>F</sub>	30	mA				
Power dissipation		P <sub>diss</sub>	50	mW				



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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
OUTPUT								
Collector emitter breakdown voltage		BV <sub>CEO</sub>	70	V				
Emitter collector breakdown voltage		BV <sub>ECO</sub>	7	V				
Power dissipation per channel		P <sub>diss</sub>	125	mW				
COUPLER								
Isolation test voltage	t = 1 s	V <sub>ISO</sub>	4000	$V_{RMS}$				
Total package dissipation ambient (2 LEDs and 2 detectors, 2 channels)		P <sub>tot</sub>	350	mW				
Storage temperature		T <sub>stg</sub>	- 55 to + 150	°C				
Operating temperature		T <sub>amb</sub>	- 55 to + 100	°C				
Soldering time from 260 °C <sup>(1)</sup>		T <sub>sld</sub>	10	S				

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	$I_F = 10 \text{ mA}$		$V_{F}$		1.2	1.55	V	
Reverse current	$V_R = 6 V$		I <sub>R</sub>		0.1	100	μA	
Capacitance	$V_R = 0 V$		Co		25		pF	
OUTPUT								
Collector emitter breakdown voltage	$I_C = 10 \mu A$		BV <sub>CEO</sub>	70			V	
Emitter collector breakdown voltage	I <sub>E</sub> = 10 μA		BV <sub>ECO</sub>	7			V	
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ A}$		I <sub>CEO</sub>		5	50	nA	
Collector emitter capacitance	$V_{CE} = 0 V$		C <sub>CE</sub>		10		pF	
COUPLER	COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V <sub>CEsat</sub>			0.4	V	
Capacitance (input to output)			C <sub>IO</sub>		0.5		pF	
Resistance (input to output)	_		R <sub>IO</sub>		100		GΩ	

#### Note

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
		ILD205T	CTR <sub>DC</sub>	40		80	%		
		ILD206T	CTR <sub>DC</sub>	63		125	%		
	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	ILD207T	CTR <sub>DC</sub>	100		200	%		
		ILD211T	CTR <sub>DC</sub>	20			%		
DC current transfer ratio		ILD213T	CTR <sub>DC</sub>	100			%		
		ILD205T	CTR <sub>DC</sub>	13	30		%		
	V <sub>CF</sub> = 5 V, I <sub>F</sub> = 1 mA	ILD206T	CTR <sub>DC</sub>	22	45		%		
	v <sub>CE</sub> = 5 v, i <sub>F</sub> = 1 iiiA	ILD207T	CTR <sub>DC</sub>	34	70		%		
		ILD217T	CTR <sub>DC</sub>	100	120		%		

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<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT	
Delay time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>d</sub>		3		μs	
Rise time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>r</sub>		3		μs	
Fall time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>f</sub>		4.7		μs	
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	t <sub>s</sub>		0.3		μs	
Turn-on time	$V_S$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$ , (see figure 1)	t <sub>on</sub>		6		μs	
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega,$ (see figure 1)	t <sub>off</sub>		5		μs	
Turn-on time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t <sub>on</sub>		3		μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega,$ (see figure 2)	t <sub>off</sub>		10		μs	

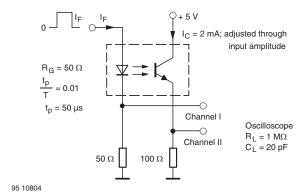


Fig. 1 - Test Circuit, Non-Saturated Operation

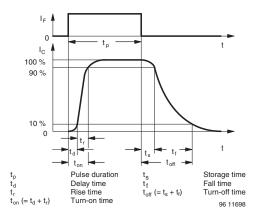


Fig. 3 - Switching Times

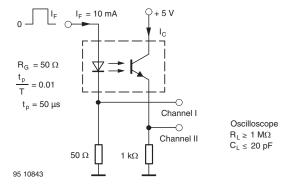


Fig. 2 - Test Circuit, Saturated Operation

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SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification (according to IEC 68 part 1)				55/100/21				
Comparative tracking index		CTI	175		399			
V <sub>IOTM</sub>			6000			V		
V <sub>IORM</sub>			560			V		
P <sub>SO</sub>					350	mW		
I <sub>SI</sub>					150	mA		
T <sub>SI</sub>					165	°C		
Creepage distance			4			mm		
Clearance distance			4			mm		
Insulation thickness			0.2			mm		

#### Note

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

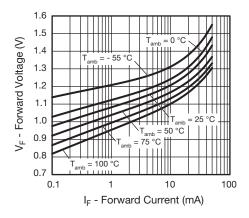


Fig. 4 - Forward Voltage vs. Forward Current

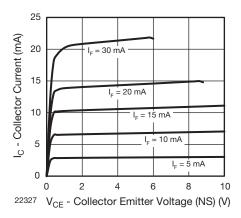


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

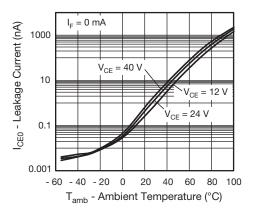


Fig. 6 - Leakage Current vs. Ambient Temperature

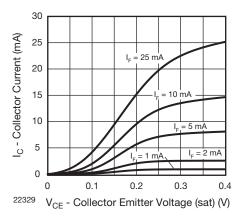


Fig. 7 - Collector Current vs. Collector Emitter Voltage (sat)

<sup>•</sup> As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

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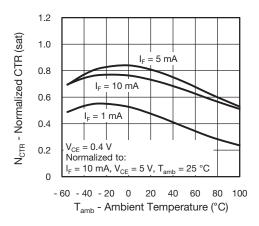


Fig. 8 - Normalized CTR (sat) vs. Ambient Temperature

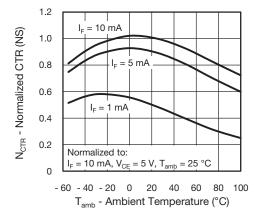


Fig. 9 - Normalized CTR (NS) vs. Ambient Temperature

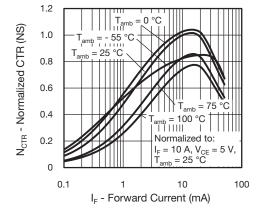


Fig. 10 - Normalized CTR (NS) vs. Forward Current

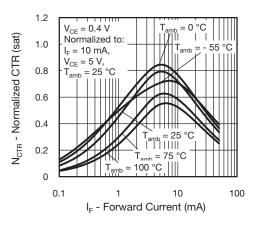


Fig. 11 - Normalized CTR (sat) vs. Forward Current

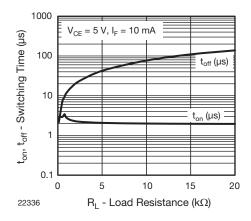


Fig. 12 - Switching Time vs. Load Resistance

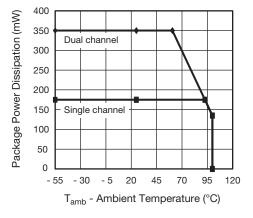


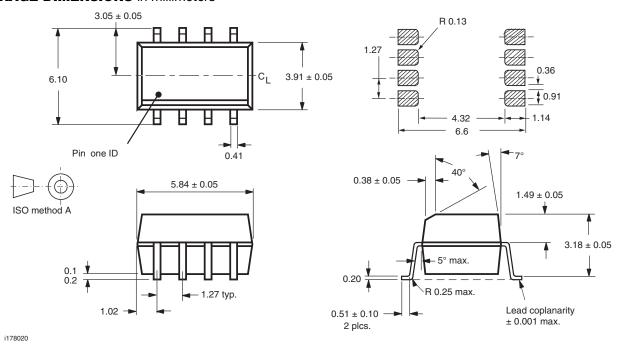
Fig. 13 - Power Dissipation vs. Ambient Temperature



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### **PACKAGE DIMENSIONS** in millimeters



### **PACKAGE MARKING** (example)



#### Note

• Tape and reel suffix (T) is not part of the package marking.



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